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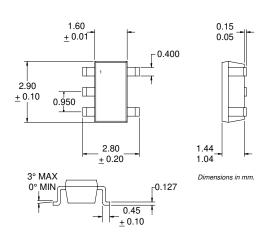
GENERAL PURPOSE AMPLIFIER

Typical Applications

- · Broadband, Low Noise Gain Blocks
- IF or RF Buffer Amplifiers
- Driver Stage for Power Amplifiers
- Final PA for Low Power Applications
- Broadband Test Equipment

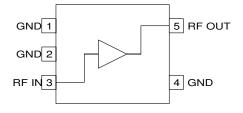
Product Description

The RF2335 is a general purpose, low-cost RF amplifier IC. The device is manufactured on an advanced Gallium Arsenide Heterojunction Bipolar Transistor (HBT) process, and has been designed for use as an easily-cascadable 50Ω gain block. Applications include IF and RF amplification in wireless voice and data communication products operating in frequency bands up to $6000\,\text{MHz}$. The device is self-contained with 50Ω input and output impedances and requires only two external DC biasing elements to operate as specified. The RF2335 is available in a very small industry-standard SOT23-5 surface mount package, enabling compact designs which conserve board space.



Optimum Technology Matching® Applied

☐ Si BJT ☐ GaAs MESFET☐ Si Bi-CMOS☐ SiGe HBT☐ Si CMOS☐ InGaP/HBT☐ GaN HEMT☐ SiGe Bi-CMOS☐



Functional Block Diagram

Package Style: SOT23-5

Features

- DC to 6000MHz Operation
- Internally matched Input and Output
- 12dB Small Signal Gain
- +33dBm Output IP3
- +17dBm Output Power
- Good Gain Flatness

Ordering Information

RF2335 General Purpose Amplifier
RF2335 PCBA Fully Assembled Evaluation Board

RF Micro Devices, Inc. 7628 Thorndike Road Greensboro, NC 27409, USA Tel (336) 664 1233 Fax (336) 664 0454 http://www.rfmd.com

RF2335

Absolute Maximum Ratings

Parameter	Rating	Unit
Input RF Power	+13	dBm
Operating Ambient Temperature	-40 to +85	°C
Storage Temperature	-60 to +150	°C



RF Micro Devices believes the furnished information is correct and accurate at the time of this printing. However, RF Micro Devices reserves the right to make changes to its products without notice. RF Micro Devices does not assume responsibility for the use of the described product(s).

Parameter	Specification		Unit	Condition		
Parameter	Min.	Тур.	Max.	Unit	Condition	
Overall					T=25°C, I _{CC} =65mA	
Frequency Range		DC to 6000		MHz		
3dB Bandwidth		3		GHz		
Gain		13.7		dB	Freq=100MHz	
		13.1		dB	Freq=1000MHz	
		12.5		dB	Freq=2000MHz	
		11		dB	Freq=3000MHz	
		10.6		dB	Freq=4000MHz	
		10		dB	Freq=5000MHz	
		9.8		dB	Freq=6000MHz	
Gain Flatness		±1		dB	100MHz to 2000MHz	
Noise Figure		5.8		dB	Freq=2000MHz	
Input VSWR		2:1			In a 50Ω system, DC to $3000 MHz$	
Output VSWR		1.7:1			In a 50Ω system, DC to 3000MHz	
Output IP ₃		+33		dBm	Freq=1000MHz±50kHz, P _{TONE} =-10dBm	
Output P _{1dB}		+17.3		dBm	Freq=1000MHz	
Reverse Isolation		17.2		dB	Freq=2000MHz	
Thermal					I _{CC} =65mA, P _{DISS} =300mW (See Note.)	
Theta _{JC}		257		°C/W		
Maximum Measured Junction Temperature		163		°C	T _{AMB} =+85°C, V _{PIN} =5V	
Mean Time Between Failures		900		years	See Note.	
Power Supply					With 22Ω bias resistor	
Device Operating Voltage		5.05		V	At pin 5 with I _{CC} =65mA	
Supply Voltage		6.5		V	At evaluation board connector, I _{CC} =65mA	
Operating Current		65	73	mA	See note.	

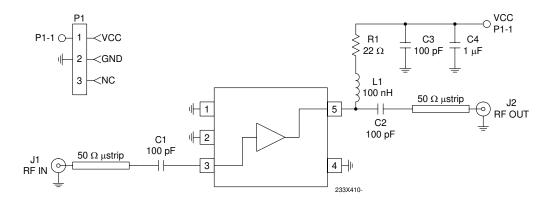
Note: Because of process variations from part to part, the current resulting from a fixed bias voltage will vary. As a result, caution should be used in designing fixed voltage bias circuits to ensure the worst case bias current does not exceed 73 mA over all intended operating conditions.

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Pin	Function	Description	Interface Schematic	
1	GND	Ground connection. For best performance, keep traces physically short and connect immediately to ground plane.		
2	GND	Same as pin 1.		
3	RF IN	RF input pin. This pin is NOT internally DC-blocked. A DC-blocking capacitor, suitable for the frequency of operation, should be used in most applications. DC coupling of the input is not allowed, because this will override the internal feedback loop and cause temperature instability.		
4	GND	Same as pin 1.		
5	RF OUT	RF output and bias pin. Biasing is accomplished with an external series resistor and choke inductor to V_{CC} . The resistor is selected to set the DC current into this pin to a desired level. The resistor value is determined by the following equation: $R = \frac{(V_{SUPPLY} - V_{DEVICE})}{I_{CC}}$ Care should also be taken in the resistor selection to ensure that the current into the part never exceeds 73mA over the planned operating temperature. This means that a resistor between the supply and this pin is always required, even if a supply near 5.0V is available, to provide DC feedback to prevent thermal runaway. Because DC is present on this pin, a DC blocking capacitor, suitable for the frequency of operation, should be used in most applications. The supply side of the bias network should also be well bypassed.	RF INO	

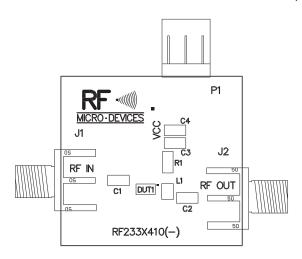
Evaluation Board Schematic

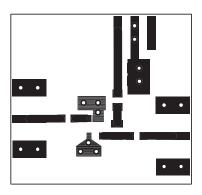
(Download Bill of Materials from www.rfmd.com.)



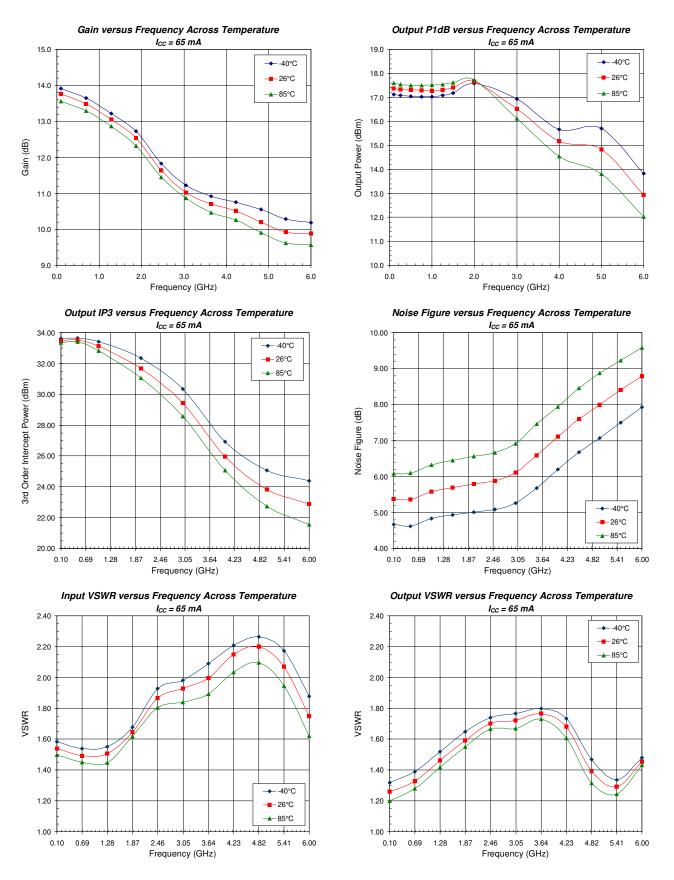
Evaluation Board Layout Board Size 1.0" x 1.0"

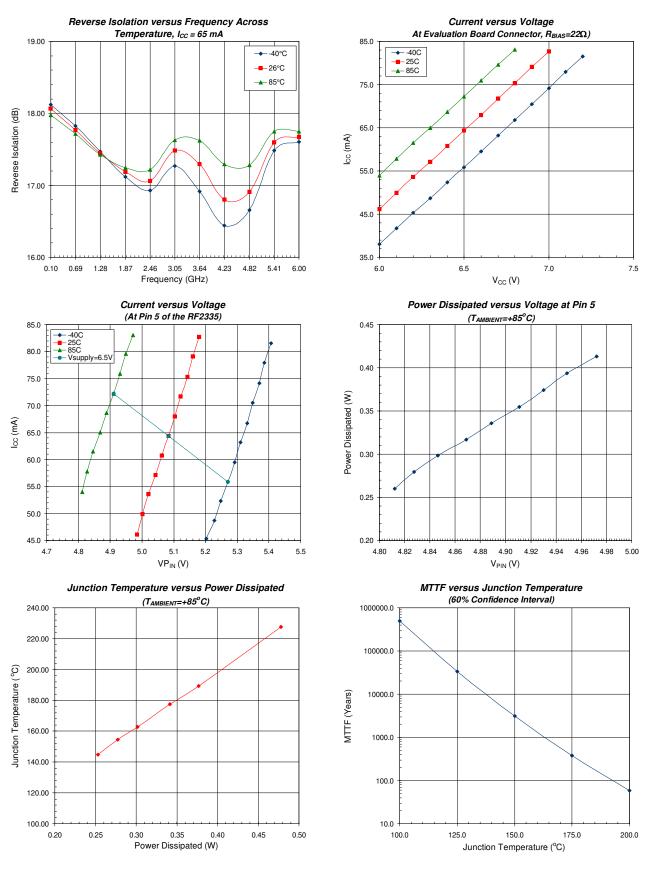
Board Thickness 0.020", Board Material R0-4003 Rogers





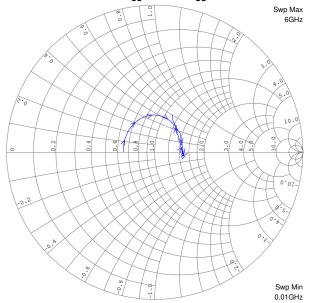
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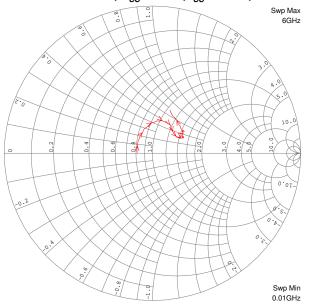


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De-Embedded S11, V_{CC} = 5.04V, I_{CC} = 65 mA, T = 25°C



De-Embedded S22, V_{CC} = 5.04V, I_{CC} = 65mA, T = 25°C



RF2335

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